

Finally the Sony-Fairchild Patent Wat(1991-2000) ended over the Sony HAD Sensor which is identical to *the P+NPNsub junction type Pinned Photodiode with Vertical Overflow Drain*, originally invented by Hagiwara at Sony in 1975.

And finally Hagiwara received for his *1975-134985 Japanese Patent* officially, the *First Patent Award* from Mr. Ando, Sony president in April, 2001 after more 26 years of struggles since his invention.



Dynamic Photo Transistor Operation
Proposed by Hagiwara at Sony in 1975

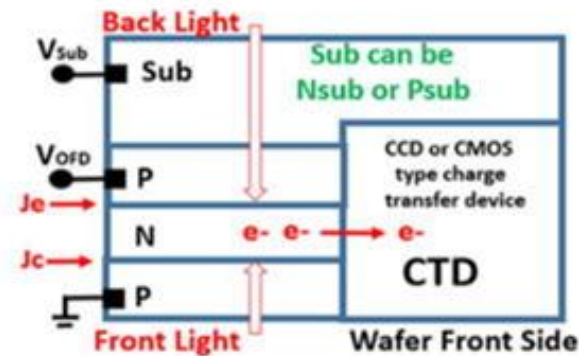
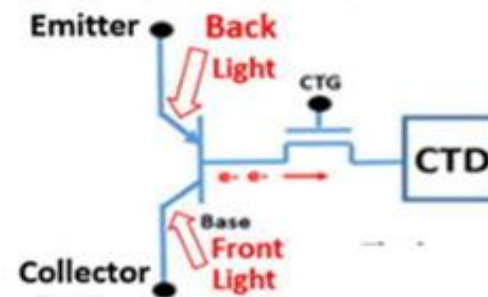


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